

## RTD60D

Silicon-Based Thermopile Detector 60 Dual

The RTD60D is a two-channel silicon-based thermopile detector in a TO-5 package. The device offers a low-cost solution, with a small active area and fast response, with a time constant of 18ms with Nitrogen encapsulation gas.

### Image Diagram



#### Features

- A two-channel silicon-based thermopile detector in a TO-5 package
- Five pin, 9.22mm TO-5 package
- Each small active area size is 0.61 × 0.61 mm
- Delivers a time constant of 18ms with Nitrogen encapsulation gas
- Very low Temperature Coefficient of Responsivity of -0.04%/°C
- Very short thermal shock response to ambient temperature change
- Internal 5% NTC chip thermistor provides ambient package temperature measurement
- Internal aperture precisely defines active area for applications with FOV and/or spot size requirements

### Benefits

- Low cost and small active area

## **Detector Circuit Overlay**





## Applications

- Gas analysis
- Fire suppression
- Non-contact temperature sensors
- Horizon sensors
- Capnography



## 1. Specifications

Specifications apply at 23°C with KBr Window and Nitrogen encapsulating gas.

Symbol	Parameter	Min	Тур.	Max.	Unit	Comments <sup>[1]</sup>
AA	Active Area size	0.61 × 0.61		mm	Hot junction size, per element.	
Α	Element Area	.37		mm <sup>2</sup>		
	Number of Junctions	80			Per element.	
	Number of Channels	2			Per detector package.	
Vs	Output Voltage	78	93	108	μV	DC, H = 330µW/cm <sup>2</sup> <sup>[2]</sup>
SNR	Signal-to-Noise Ratio	2305	2969	3981	√Hz	DC, SNR = V <sub>s</sub> /V <sub>n</sub>
R	Responsivity	63.5	75.7	88.0	V/W	DC, R = V <sub>s</sub> /HA <sup>[3]</sup>
R	Resistance	45	60	70	kΩ	Detector element
	Temperature Coefficient of $\Re$		-0.04		%/°C	Best linear fit, 0° to 85°C <sup>[4]</sup>
	Temperature Coefficient of R		0.11		%/°C	Best fit, 0° to 85°C <sup>[4]</sup>
V <sub>n</sub>	Noise Voltage	27.1	31.3	33.8	nV/√Hz	$V_n^2 = 4kTR$
NEP	Noise Equivalent Power	0.31	0.41	.53	nW/√Hz	DC, NEP = $V_n HA/V_s$ <sup>[3]</sup>
D*	Detectivity	1.15	1.47	1.98	10 <sup>8</sup> cm√Hz/Ω	DC, D* = V <sub>s</sub> / V <sub>n</sub> H\/A <sup>[3]</sup>
Т	Time Constant		18		ms	Chopped, -3dB point <sup>[4]</sup>
FOV	Field of View	24°/52°		Degrees	For FOV description, see Package Outline Drawings	
М	Element Matching		5	10	%	$\mathcal{H} =  V_{A} - V_{B}  / V_{B} $ <sup>[3]</sup>
	Element Separation		3.02		mm	Center to center
	Package Type		TO-5			Standard package hole size: 0.060" × 0.060"
T <sub>a</sub>	Operating Temperature	-50		+100	°C	
	Reference Filter, Central Wave Length		3.920		μm	Element A
	CO2 Filter, Central Wave Length		4.260		μm	Element B

1. General specifications: Flat spectral response from 100nm to > 100μm. Linear signal output from 10<sup>-6</sup> to 0.1W/cm<sup>2</sup>. Maximum incident radiance 0.1W/cm<sup>2</sup>, damage threshold ≥ .5W/cm<sup>2</sup>.

2. Test conditions: 500K Blackbody source; Detector active surface 10cm from 0.6513cm diameter Blackbody Aperture.

3. A is detector area in  $mm^2$ .

4. Parameter is not 100% tested. 90% of all units meet these specifications.



# 2. Package Outline Drawings









Figure 2. Package Outline Drawings – Side View

## 3. Ordering Information

Orderable Part Number Package		Temperature	Carrier Type
RH5Z0622D20GZO#ADO	9.22mm TO-5 package	-50 to +100°C	Tray

## 4. Revision History

Revision	Date	Description
1.00	Aug 31, 2021	Initial release.



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